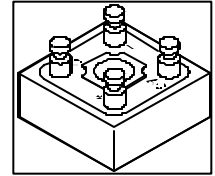


TECHNICAL DATA  
DATA SHEET 4030, REV. -

**SUPER FAST SINGLE PHASE FULL WAVE  
BRIDGE RECTIFIER ASSEMBLY**



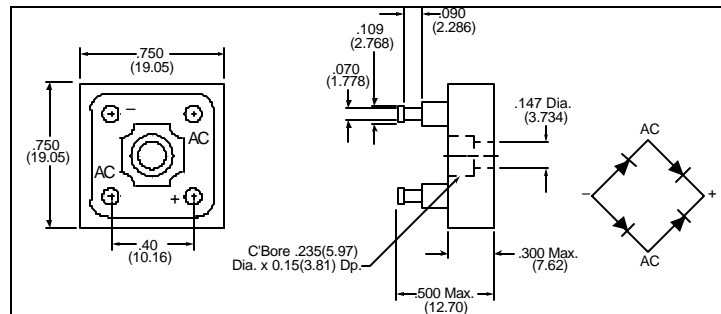
**DESCRIPTION: A 600-VOLT, 9 AMP, 70 NANOSECOND SINGLE PHASE BRIDGE RECTIFIER ASSEMBLY.**

**MAX. RATINGS / ELECTRICAL CHARACTERISTICS** All ratings are at  $T_A = 25^\circ\text{C}$  unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	600	Vdc
Average DC Output Current ( $I_o$ )	$T_C = 55^\circ\text{C}$ $T_C = 100^\circ\text{C}$	-	-	9 6.75	Amps
Average DC Output Current Ambient Temp. (no heat sink) ( $I_o$ )	$T_A = 25^\circ\text{C}$ $T_A = 55^\circ\text{C}$ $T_A = 100^\circ\text{C}$	-	-	3.5 2.5 2.0	Amps
Peak Single Cycle Surge Current ( $I_{FSM}$ )	$t_p = 8.3$ ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	100	Amps(pk)
Peak Recurring Surge Current ( $I_{FRM}$ )	$T_C = 25^\circ\text{C}$	-	-	30	Amps
Operating and Storage Temp. ( $T_{op}$ & $T_{stg}$ )	-	-55	-	+150	$^\circ\text{C}$
Maximum Forward Voltage per leg ( $V_f$ )	$I_f = 9.0\text{A}$ (300 $\mu\text{sec}$ pulse, duty cycle < 2%)	-	-	1.75	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	-	-	20 200	$\mu\text{Amps}$
Reverse Recovery Time ( $t_{rr}$ )	$I_f = 0.5\text{A}$ , $I_r = 1.0\text{A}$ , $I_{rr} = 0.25\text{A}$	-	-	70	nsec
Thermal Resistance ( $\theta_{JC}$ )	-	-	-	2.0	$^\circ\text{C/W}$

**TECHNICAL DATA**  
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**MECHANICAL DIMENSIONS: In Inches / mm**



**FIG. 401**

Note: Case finish - Black Anodized

**TECHNICAL DATA**

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